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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details	
Product Status	Obsolete
Core Processor	F ² MC-16LX
Core Size	16-Bit
Speed	24MHz
Connectivity	CANbus, EBI/EMI, I ² C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, WDT
Number of I/O	51
Program Memory Size	128KB (128K x 8)
Program Memory Type	Mask ROM
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	3.5V ~ 5.5V
Data Converters	A/D 15x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb90352espmc-gs-246e1

(Continued)

Part Number Parameter	MB90F356E MB90F357E	MB90F356TE MB90F357TE	MB90F356ES MB90F357ES	MB90F356TES MB90F357TES
16-bit input capture	6 channels Retains 16-bit free-run timer value by (rising edge, falling edge or rising & falling edge), signals an interrupt.			
8/16-bit programmable pulse generator	6 channels (16-bit)/10 channels (8-bit) 8-bit reload counters × 12 8-bit reload registers for L pulse width×12 8-bit reload registers for H pulse width×12 Supports 8-bit and 16-bit operation modes. A pair of 8-bit reload counters can be configured as one 16-bit reload counter or as 8-bit prescaler + 8-bit reload counter. Operation clock frequency : fsys, fsys/2 ¹ , fsys/2 ² , fsys/2 ³ , fsys/2 ⁴ or 128 μs@fosc = 4 MHz (fsys = Machine clock frequency, fosc = Oscillation clock frequency)			
CAN interface	1 channel Conforms to CAN Specification Version 2.0 Part A and B. Automatic re-transmission in case of error Automatic transmission responding to Remote Frame Prioritized 16 message buffers for data and ID Supports multiple messages. Flexible configuration of acceptance filtering : Full bit compare/Full bit mask/Two partial bit masks Supports up to 1 Mbps.			
External interrupt	8 channels Can be used rising edge, falling edge, starting up by H/L level input, external interrupt, extended intelligent I/O services (EI ² OS) and DMA.			
D/A converter	—			
I/O ports	Virtually all external pins can be used as general purpose I/O port. All push-pull outputs Bit-wise settable as input/output or peripheral module signal Settable as CMOS schmitt trigger/ automotive inputs TTL input level settable for external bus (only for external bus pin)			
Flash memory	Supports automatic programming, Embedded Algorithm Write/Erase/Erase-Suspend/Resume commands A flag indicating completion of the algorithm Number of erase cycles : 10000 times Data retention time : 20 years Boot block configuration Erase can be performed on each block. Block protection with external programming voltage Flash Security Feature for protecting the content of the Flash (MB90F357x only)			
Corresponding EVA name	MB90V340E-104		MB90V340E-103	

* : It is setting of Jumper switch (TOOL VCC) when Emulator (MB2147-01) is used.
Please refer to the Emulator hardware manual about details.

3. Packages and Product Correspondence

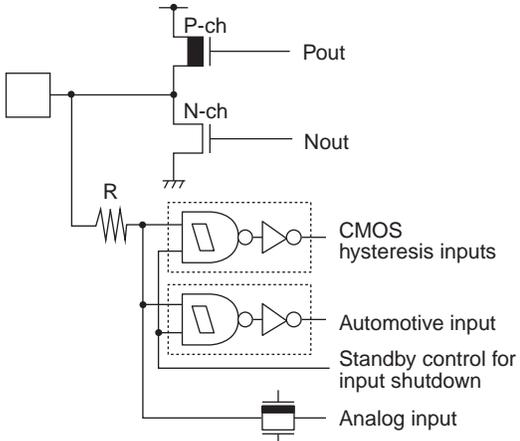
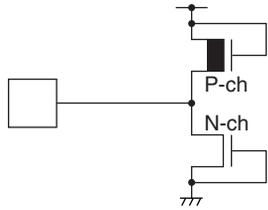
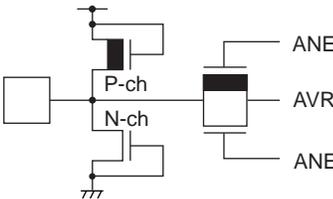
Package	MB90V340E-101 MB90V340E-102 MB90V340E-103 MB90V340E-104	MB90351E (S) , MB90351TE (S) MB90F351E (S) , MB90F351TE (S) MB90352E (S) , MB90352TE (S) MB90F352E (S) , MB90F352TE (S) MB90356E (S) , MB90356TE (S) MB90F356E (S) , MB90F356TE (S) MB90357E (S) , MB90357TE (S) MB90F357E (S) , MB90F357TE (S)
PGA-299C-A01	○	×
FPT-64P-M23 (12.0 mm □, 0.65 mm pitch)	×	○
FPT-64P-M24 (10.0 mm □, 0.50 mm pitch)	×	○

○ : Yes, × : No

Note : Refer to “[Package Dimensions](#)” for detail of each package.

Pin No.	Pin name	I/O Circuit type*	Function
54	P30	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled in single-chip mode.
	ALE		Address latch enable output pin. This function is enabled when external bus is enabled.
	IN4		Data sample input pin for input capture ICU4
55	P31	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled in single-chip mode.
	\overline{RD}		Read strobe output pin for data bus. This function is enabled when external bus is enabled.
	IN5		Data sample input pin for input capture ICU5
56	P32	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled either in single-chip mode or with the $\overline{WR/WRL}$ pin output disabled.
	$\overline{WR/WRL}$		Write strobe output pin for the data bus. This function is enabled when both the external bus and the $\overline{WR/WRL}$ pin output are enabled. \overline{WRL} is used to write-strobe 8 lower bits of the data bus in 16-bit access. \overline{WR} is used to write-strobe 8 bits of the data bus in 8-bit access.
	INT10R		External interrupt request input pin for INT10
57	P33	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled either in single-chip mode, in external bus 8-bit mode or with the \overline{WRH} pin output disabled.
	\overline{WRH}		Write strobe output pin for the 8 higher bits of the data bus. This function is enabled when the external bus is enabled, when the external bus 16-bit mode is selected, and when the \overline{WRH} output pin is enabled.
58	P34	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled either in single-chip mode or with the hold function disabled.
	HRQ		Hold request input pin. This function is enabled when both the external bus and the hold function are enabled.
	OUT4		Wave form output pin for output compare OCU4
59	P35	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled either in single-chip mode or with the hold function disabled.
	\overline{HAK}		Hold acknowledge output pin. This function is enabled when both the external bus and the hold function are enabled.
	OUT5		Wave form output pin for output compare OCU5
60	P36	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled either in single-chip mode or with the external ready function disabled.
	RDY		Ready input pin. This function is enabled when both the external bus and the external ready function are enabled.
	OUT6		Wave form output pin for output compare OCU6

(Continued)

Type	Circuit	Remarks
I		<ul style="list-style-type: none"> ■ CMOS level output ($I_{OL} = 4 \text{ mA}$, $I_{OH} = -4 \text{ mA}$) ■ CMOS hysteresis inputs (With the standby-time input shutdown function) ■ Automotive input (With the standby-time input shutdown function) ■ Analog input for A/D converter
K		<p>Protection circuit for power supply input</p>
L		<ul style="list-style-type: none"> ■ With the protection circuit of A/D converter reference voltage power input pin ■ Flash memory devices do not have a protection circuit against V_{CC} for pin AVRH.

(Continued)

During an internal RAM write cycle, low voltage reset is generated after the completion of writing. During the output of this internal reset, the reset output from the low voltage detection reset circuit is suppressed.

(2) CPU operation detection reset circuit

The CPU operation detection reset circuit is a counter that prevents program runaway. The counter starts automatically after a power-on reset, and must be continually and regularly cleared within a given time. If the given time interval elapses and the counter has not been cleared, a cause such as infinite program looping is assumed and an internal reset signal is generated. The internal reset generated from the CPU operation detection circuit has a width of 5 machine cycles.

Interval time
$2^{20}/F_C$ (approx. 262 ms*)

* : This value assumes the interval time at an oscillation clock frequency of 4 MHz.

During recovery from standby mode, the detection period is the maximum interval plus 20 μ s.

This circuit does not operate in modes where CPU operation is stopped.

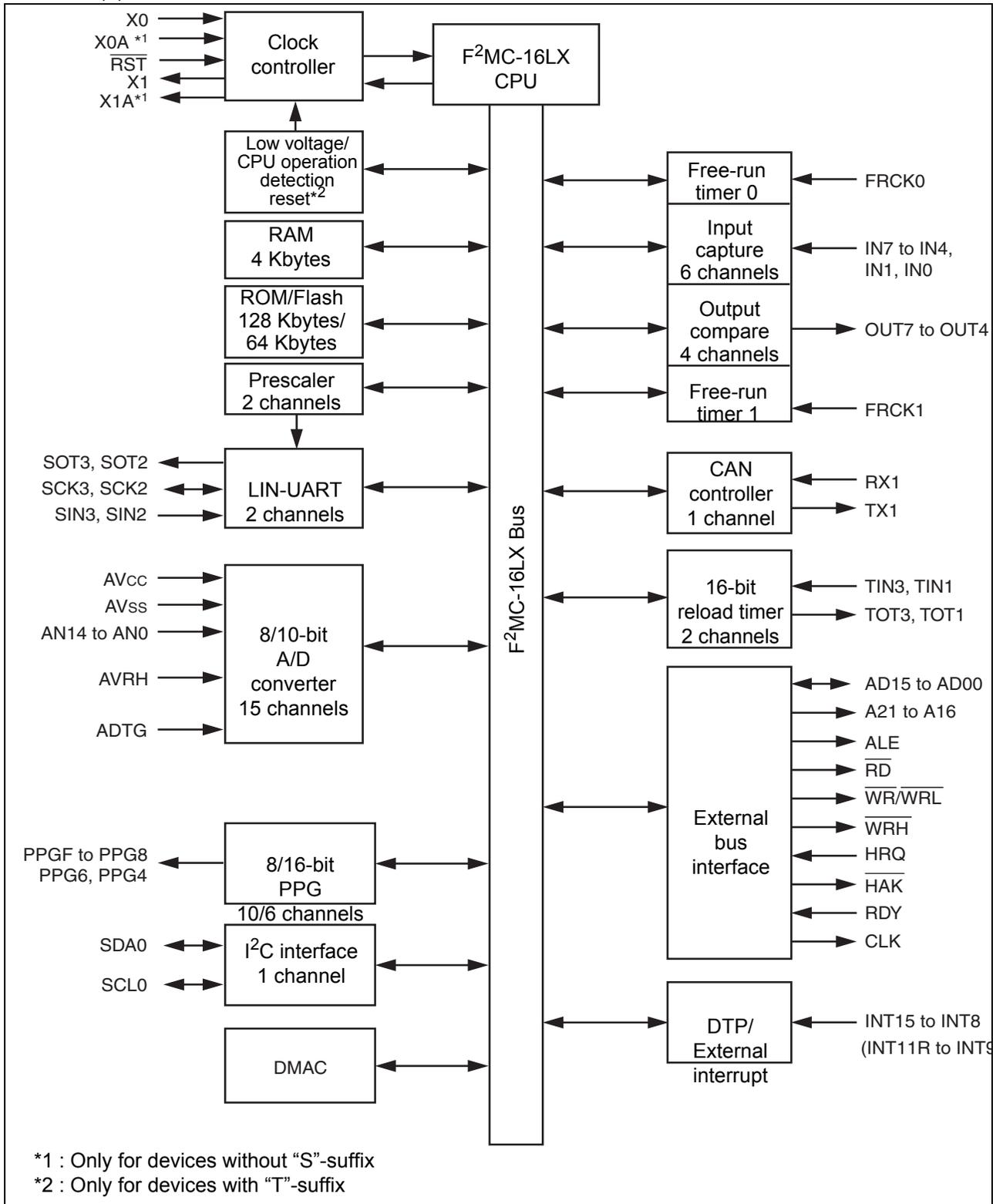
The CPU operation detection reset circuit counter is cleared under any of the following conditions.

- “0” writing to CL bit of LVRC register
- Internal reset
- Main oscillation clock stop
- Transit to sleep mode
- Transit to timebase timer mode and watch mode

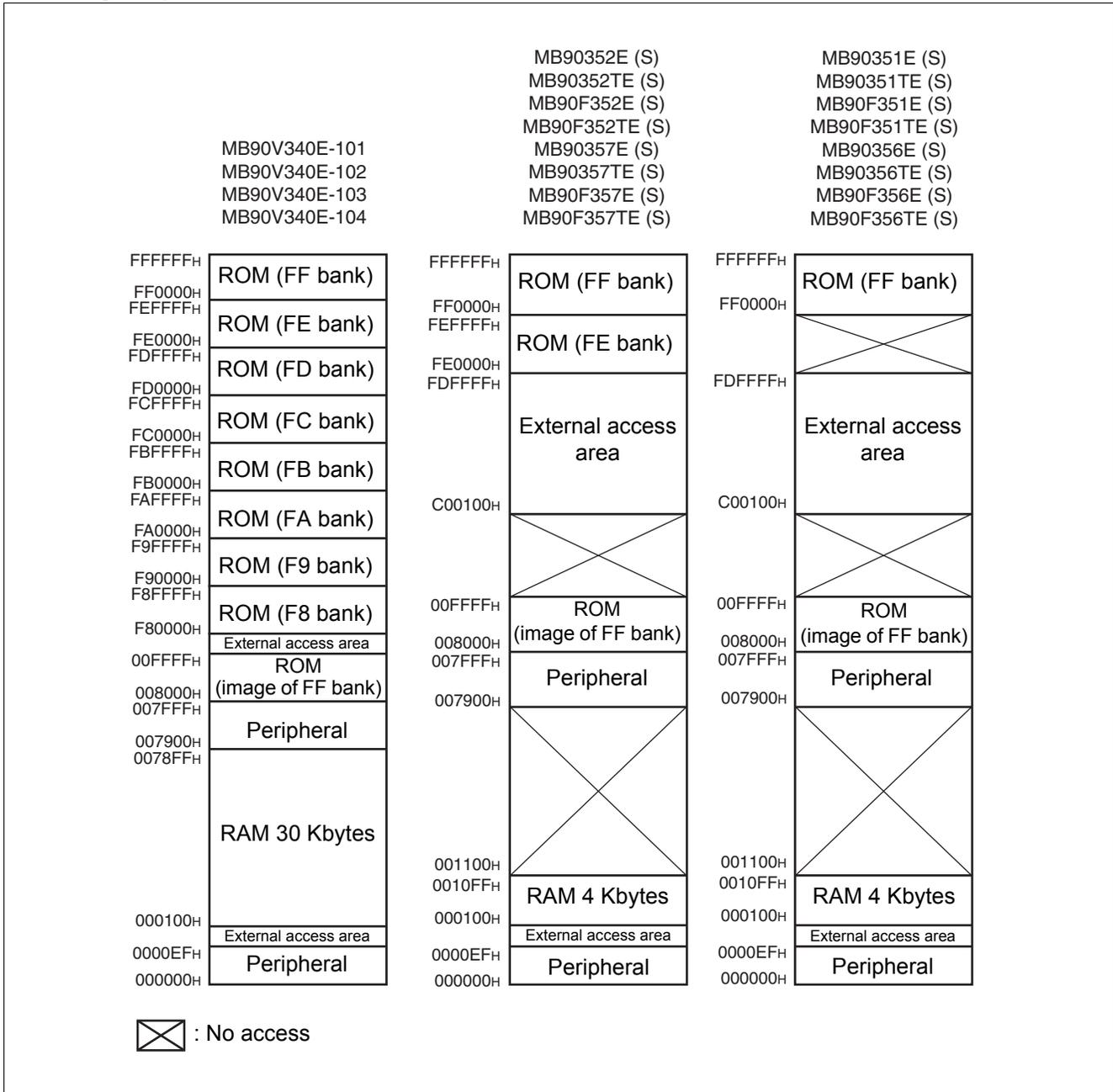
19. Internal CR oscillation circuit

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Oscillation frequency	f_{RC}	50	100	200	kHz
Oscillation stabilization wait time	tstab	—	—	100	μ s

- MB90351E (S) , MB90351TE (S) , MB90F351E (S) , MB90F351TE (S) , MB90352E (S) , MB90352TE (S) , MB90F352E (S) , MB90F352TE (S)



9. Memory Map



Note : The high-order portion of bank 00 gives the image of the FF bank ROM to make the small model of the C compiler effective. Since the low-order 16 bits are the same, the table in ROM can be referenced without using the far specification in the pointer declaration. For example, an attempt to access 00C000_H practically accesses the value at FFC000_H in ROM. The ROM area in bank FF exceeds 32 Kbytes, and its entire image cannot be shown in bank 00. The image between FF8000_H and FFFFFFF_H is visible in bank 00, while the image between FF0000_H and FF7FFF_H is visible only in bank FF.

Address	Register	Abbreviation	Access	Resource name	Initial value
000038 _H	PPG 4 Operation Mode Control Register	PPGC4	W, R/W	16-bit Programmable Pulse Generator 4/5	0X000XX1 _B
000039 _H	PPG 5 Operation Mode Control Register	PPGC5	W, R/W		0X000001 _B
00003A _H	PPG 4/5 Count Clock Select Register	PPG45	R/W		000000X0 _B
00003B _H	Address Detect Control Register 1	PACSR1	R/W	Address Match Detection 1	00000000 _B
00003C _H	PPG 6 Operation Mode Control Register	PPGC6	W, R/W	16-bit Programmable Pulse Generator 6/7	0X000XX1 _B
00003D _H	PPG 7 Operation Mode Control Register	PPGC7	W, R/W		0X000001 _B
00003E _H	PPG 6/7 Count Clock Select Register	PPG67	R/W		000000X0 _B
00003F _H	Reserved				
000040 _H	PPG 8 Operation Mode Control Register	PPGC8	W, R/W	16-bit Programmable Pulse Generator 8/9	0X000XX1 _B
000041 _H	PPG 9 Operation Mode Control Register	PPGC9	W, R/W		0X000001 _B
000042 _H	PPG 8/9 Count Clock Select Register	PPG89	R/W		000000X0 _B
000043 _H	Reserved				
000044 _H	PPG A Operation Mode Control Register	PPGCA	W, R/W	16-bit Programmable Pulse Generator A/B	0X000XX1 _B
000045 _H	PPG B Operation Mode Control Register	PPGCB	W, R/W		0X000001 _B
000046 _H	PPG A/B Count Clock Select Register	PPGAB	R/W		000000X0 _B
000047 _H	Reserved				
000048 _H	PPG C Operation Mode Control Register	PPGCC	W,R/W	16-bit Programmable Pulse Generator C/D	0X000XX1 _B
000049 _H	PPG D Operation Mode Control Register	PPGCD	W,R/W		0X000001 _B
00004A _H	PPG C/D Count Clock Select Register	PPGCD	R/W		000000X0 _B
00004B _H	Reserved				
00004C _H	PPG E Operation Mode Control Register	PPGCE	W,R/W	16-bit Programmable Pulse Generator E/F	0X000XX1 _B
00004D _H	PPG F Operation Mode Control Register	PPGCF	W,R/W		0X000001 _B
00004E _H	PPG E/F Count Clock Select Register	PPGEF	R/W		000000X0 _B
00004F _H	Reserved				
000050 _H	Input Capture Control Status Register 0/1	ICS01	R/W	Input Capture 0/1	00000000 _B
000051 _H	Input Capture Edge Register 0/1	ICE01	R/W, R		XXX0X0XX _B
000052 _H , 000053 _H	Reserved				
000054 _H	Input Capture Control Status Register 4/5	ICS45	R/W	Input Capture 4/5	00000000 _B
000055 _H	Input Capture Edge Register 4/5	ICE45	R		XXXXXXXX _B
000056 _H	Input Capture Control Status Register 6/7	ICS67	R/W	Input Capture 6/7	00000000 _B
000057 _H	Input Capture Edge Register 6/7	ICE67	R/W, R		XXX000XX _B

(Continued)

Address	Register	Abbreviation	Access	Resource name	Initial value
007950 _H	Serial Mode Register 3	SMR3	W, R/W	UART3	00000000 _B
007951 _H	Serial Control Register 3	SCR3	W, R/W		00000000 _B
007952 _H	Reception/Transmission Data Register 3	RDR3/TDR3	R/W		00000000 _B
007953 _H	Serial Status Register 3	SSR3	R,R/W		00001000 _B
007954 _H	Extended Communication Control Register 3	ECCR3	R,W, R/W		000000XX _B
007955 _H	Extended Status Control Register 3	ESCR3	R/W		00000100 _B
007956 _H	Baud Rate Generator Register 30	BGR30	R/W		00000000 _B
007957 _H	Baud Rate Generator Register 31	BGR31	R/W		00000000 _B
007958 _H , 007959 _H	Reserved				
007960 _H	Clock supervisor Control Register	CSVCR	R, R/W	Clock Supervisor	00011100 _B
007961 _H to 00796D _H	Reserved				
00796E _H	CAN Direct Mode Register	CDMR	R/W	CAN Clock Sync	XXXXXXXX0 _B
00796F _H	Reserved				
007970 _H	I ² C Bus Status Register 0	IBSR0	R	I ² C Interface 0	00000000 _B
007971 _H	I ² C Bus Control Register 0	IBCR0	W,R/W		00000000 _B
007972 _H	I ² C 10-bit Slave Address Register 0	ITBAL0	R/W		00000000 _B
007973 _H		ITBAH0	R/W		00000000 _B
007974 _H	I ² C 10-bit Slave Address Mask Register 0	ITMKL0	R/W		11111111 _B
007975 _H		ITMKH0	R/W		00111111 _B
007976 _H	I ² C 7-bit Slave Address Register 0	ISBA0	R/W		00000000 _B
007977 _H	I ² C 7-bit Slave Address Mask Register 0	ISMK0	R/W		01111111 _B
007978 _H	I ² C data register 0	IDAR0	R/W	00000000 _B	
007979 _H , 00797A _H	Reserved				
00797B _H	I ² C Clock Control Register 0	ICCR0	R/W	I ² C Interface 0	00011111 _B
00797C _H to 0079A1 _H	Reserved				
0079A2 _H	Flash Write Control Register 0	FWR0	R/W	Dual Operation Flash	00000000 _B
0079A3 _H	Flash Write Control Register 1	FWR1	R/W		00000000 _B
0079A4 _H	Sector Change Setting Register 0	SSR0	R/W		00XXXXX0 _B
0079A5 _H to 0079C1 _H	Reserved				
0079C2 _H	Clock modulator Control Register	CMCR	R, R/W	Clock Modulator	0001X000 _B

(Continued)

List of Message Buffers (DLC Registers and Data Registers)

Address	Register	Abbreviation	Access	Initial Value
CAN1				
007C60 _H	DLC register 0	DLCR0	R/W	XXXXXXXX _B
007C61 _H				
007C62 _H	DLC register 1	DLCR1	R/W	XXXXXXXX _B
007C63 _H				
007C64 _H	DLC register 2	DLCR2	R/W	XXXXXXXX _B
007C65 _H				
007C66 _H	DLC register 3	DLCR3	R/W	XXXXXXXX _B
007C67 _H				
007C68 _H	DLC register 4	DLCR4	R/W	XXXXXXXX _B
007C69 _H				
007C6A _H	DLC register 5	DLCR5	R/W	XXXXXXXX _B
007C6B _H				
007C6C _H	DLC register 6	DLCR6	R/W	XXXXXXXX _B
007C6D _H				
007C6E _H	DLC register 7	DLCR7	R/W	XXXXXXXX _B
007C6F _H				
007C70 _H	DLC register 8	DLCR8	R/W	XXXXXXXX _B
007C71 _H				
007C72 _H	DLC register 9	DLCR9	R/W	XXXXXXXX _B
007C73 _H				
007C74 _H	DLC register 10	DLCR10	R/W	XXXXXXXX _B
007C75 _H				
007C76 _H	DLC register 11	DLCR11	R/W	XXXXXXXX _B
007C77 _H				
007C78 _H	DLC register 12	DLCR12	R/W	XXXXXXXX _B
007C79 _H				
007C7A _H	DLC register 13	DLCR13	R/W	XXXXXXXX _B
007C7B _H				
007C7C _H	DLC register 14	DLCR14	R/W	XXXXXXXX _B
007C7D _H				
007C7E _H	DLC register 15	DLCR15	R/W	XXXXXXXX _B
007C7F _H				

(Continued)

(Continued)

Address	Register	Abbreviation	Access	Initial Value
CAN1				
007CF0 _H to 007CF7 _H	Data register 14 (8 bytes)	DTR14	R/W	XXXXXXXX _B to XXXXXXXX _B
007CF8 _H to 007CFF _H	Data register 15 (8 bytes)	DTR15	R/W	XXXXXXXX _B to XXXXXXXX _B

13.4 AC Characteristics
13.4.1 Clock Timing
 $(T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, f_{CP} \leq 24\text{ MHz}, V_{SS} = AV_{SS} = 0\text{ V})$

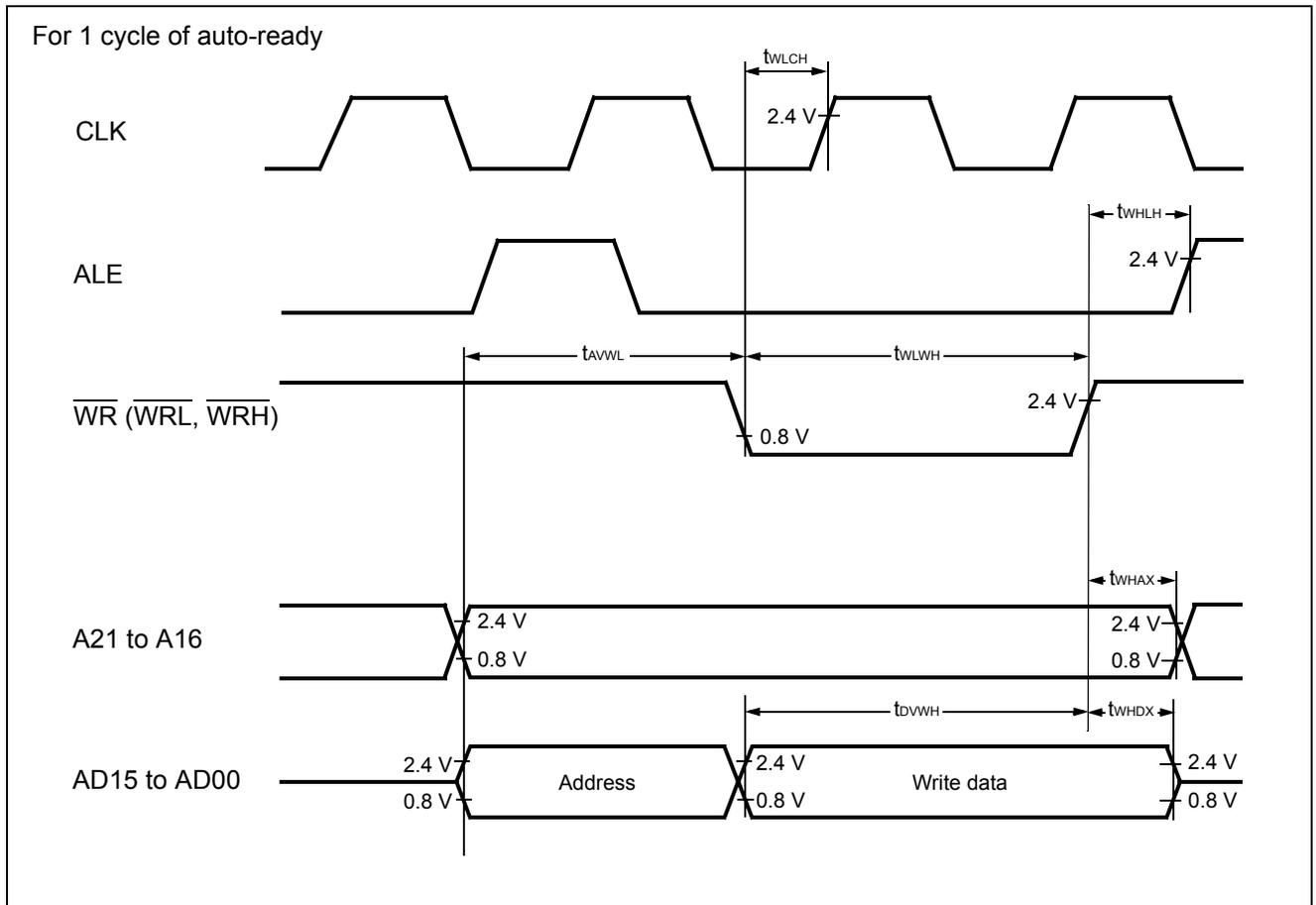
Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Clock frequency	f_C	X0, X1	3	—	16	MHz	1/2 (at PLL stop) When using an oscillation circuit
			4	—	16	MHz	1 multiplied PLL When using an oscillation circuit
			4	—	12	MHz	2 multiplied PLL When using an oscillation circuit
			4	—	8	MHz	3 multiplied PLL When using an oscillation circuit
			4	—	6	MHz	4 multiplied PLL When using an oscillation circuit
			—	—	4	MHz	6 multiplied PLL When using an oscillation circuit
		X0	3	—	24	MHz	1/2 (at PLL stop), When using an external clock
			4	—	24	MHz	1 multiplied PLL When using an external clock
			4	—	12	MHz	2 multiplied PLL When using an external clock
			4	—	8	MHz	3 multiplied PLL When using an external clock
			4	—	6	MHz	4 multiplied PLL When using an external clock
			—	—	4	MHz	6 multiplied PLL When using an external clock
	fCL	X0A, X1A	—	32.768	100	kHz	When using sub clock
Clock cycle time	t_{CYL}	X0, X1	62.5	—	333	ns	When using an oscillation circuit
		X0	41.67	—	333	ns	When using an external clock
	t_{CYLL}	X0A, X1A	10	30.5	—	μs	
Input clock pulse width	P_{WH}, P_{WL}	X0	10	—	—	ns	Duty ratio should be about 30% to 70%.
	P_{WHL}, P_{WLL}	X0A	5	15.2	—	μs	
Input clock rise and fall time	t_{CR}, t_{CF}	X0	—	—	5	ns	When using an external clock

(Continued)

13.4.6 Bus Timing (Write)
 $(T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, V_{SS} = 0.0\text{ V}, f_{CP} \leq 24\text{ MHz})$

Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Valid address $\rightarrow \overline{\text{WR}} \downarrow$ time	t_{AVWL}	A21 to A16, AD15 to AD00, $\overline{\text{WR}}$	-	$t_{\text{CP}} - 15$	-	ns
$\overline{\text{WR}}$ pulse width	t_{WLWH}	$\overline{\text{WR}}$		$(n^* + 3/2)t_{\text{CP}} - 20$	-	ns
Valid data output $\rightarrow \overline{\text{WR}} \uparrow$ time	t_{DVWH}	AD15 to AD00, $\overline{\text{WR}}$		$(n^* + 3/2)t_{\text{CP}} - 20$	-	ns
$\overline{\text{WR}} \uparrow \rightarrow$ Data hold time	t_{WHDX}	AD15 to AD00, $\overline{\text{WR}}$		15	-	ns
$\overline{\text{WR}} \uparrow \rightarrow$ Address valid time	t_{WHAX}	A21 to A16, $\overline{\text{WR}}$		$t_{\text{CP}}/2 - 10$	-	ns
$\overline{\text{WR}} \uparrow \rightarrow$ ALE \uparrow time	t_{WHLH}	$\overline{\text{WR}}$, ALE		$t_{\text{CP}}/2 - 15$	-	ns
$\overline{\text{WR}} \downarrow \rightarrow$ CLK \uparrow time	t_{WLCH}	$\overline{\text{WR}}$, CLK		$t_{\text{CP}}/2 - 15$	-	ns

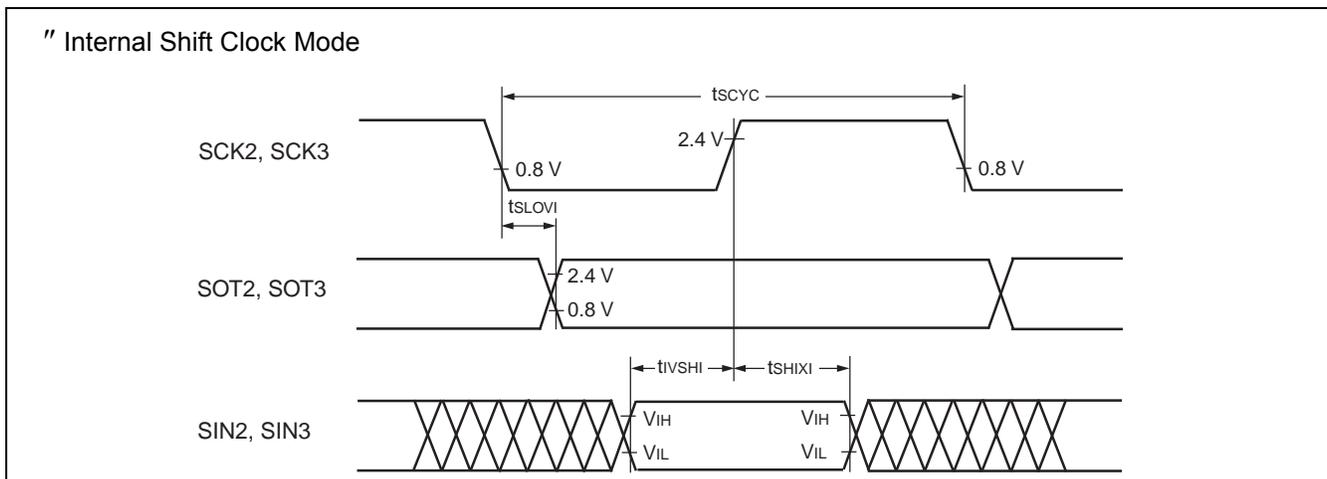
* : Number of ready cycles

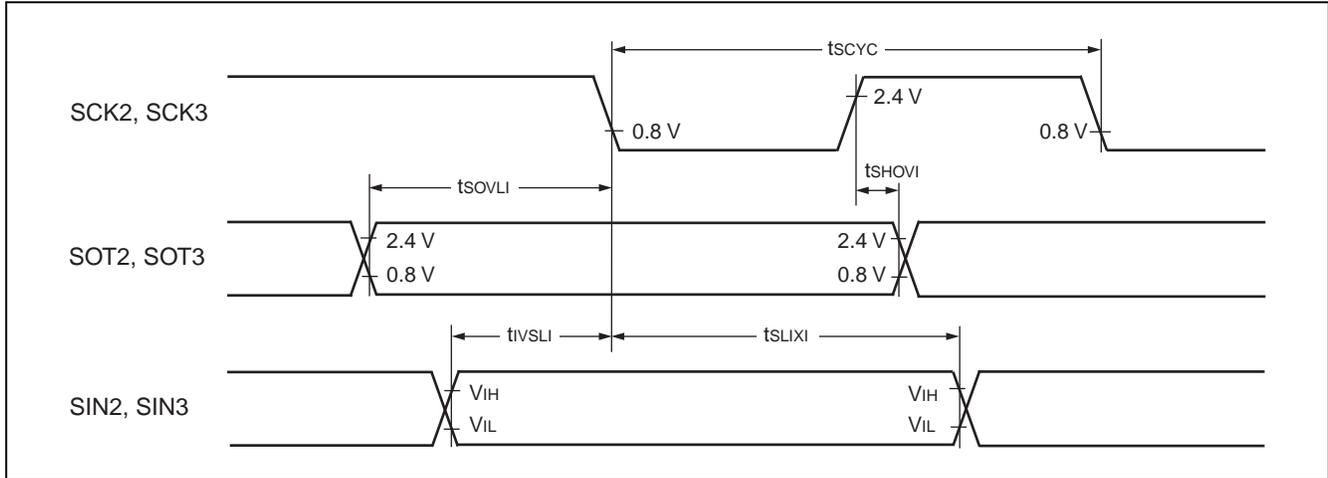


13.4.9 LIN-UART2/3
■ Bit setting: ESCR:SCES = 0, ECCR:SCDE = 0
 $(T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, f_{CP} \leq 24\text{ MHz}, V_{SS} = 0\text{ V})$

Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t_{SCYC}	SCK2, SCK3	Internal shift clock mode output pins are $CL = 80\text{ pF} + 1\text{ TTL}$.	$5 t_{CP}$	—	ns
SCK ↓ → SOT delay time	t_{SLOVI}	SCK2, SCK3 SOT2, SOT3		-50	+50	ns
Valid SIN → SCK ↑	t_{IVSHI}	SCK2, SCK3 SIN2, SIN3		$t_{CP} + 80$	—	ns
SCK ↑ → Valid SIN hold time	t_{SHIXI}	SCK2, SCK3 SIN2, SIN3		0	—	ns
Serial clock "L" pulse width	t_{SHSL}	SCK2, SCK3	External shift clock mode output pins are $CL = 80\text{ pF} + 1\text{ TTL}$.	$3 t_{CP} - t_R$	—	ns
Serial clock "H" pulse width	t_{SLSH}	SCK2, SCK3		$t_{CP} + 10$	—	ns
SCK ↓ → SOT delay time	t_{SLOVE}	SCK2, SCK3 SOT2, SOT3		—	$2 t_{CP} + 60$	ns
Valid SIN → SCK ↑	t_{IVSHE}	SCK2, SCK3 SIN2, SIN3		30	—	ns
SCK ↑ → Valid SIN hold time	t_{SHIXE}	SCK2, SCK3 SIN2, SIN3		$t_{CP} + 30$	—	ns
SCK fall time	t_F	SCK2, SCK3		—	10	ns
SCK rise time	t_R	SCK2, SCK3		—	10	ns

- Notes :
- AC characteristic in CLK synchronized mode.
 - C_L is load capacity value of pins when testing.
 - t_{CP} is internal operating clock cycle time (machine clock) . Refer to "Clock Timing".



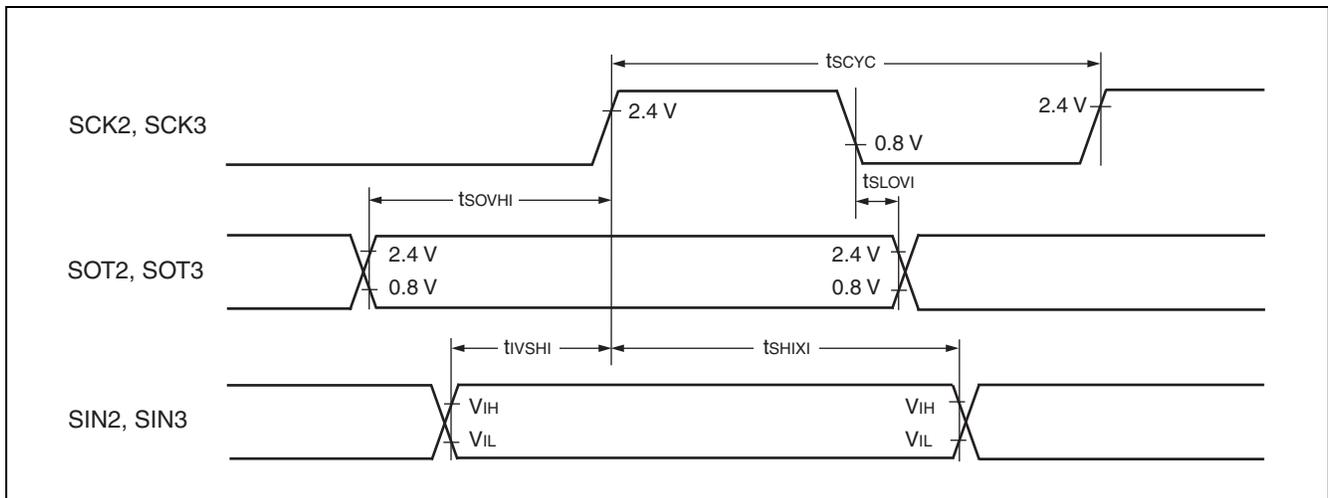


■ Bit setting: ESCR:SCES = 1, ECCR:SCDE = 1

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$, $f_{CP} \leq 24\text{ MHz}$, $V_{SS} = 0\text{ V}$)

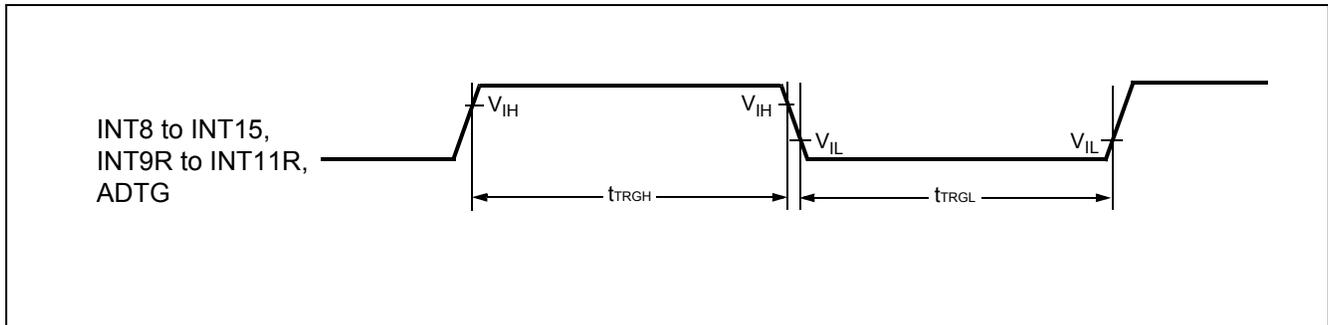
Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t_{SCYC}	SCK2, SCK3	Internal clock operation output pins are $CL = 80\text{ pF} + 1\text{ TTL}$.	$5 t_{CP}$	—	ns
SCK $\downarrow \rightarrow$ SOT delay time	t_{SLOVI}	SCK2, SCK3 SOT2, SOT3		-50	+50	ns
Valid SIN \rightarrow SCK \uparrow	t_{IVSHI}	SCK2, SCK3 SIN2, SIN3		$t_{CP} + 80$	—	ns
SCK $\uparrow \rightarrow$ Valid SIN hold time	t_{SHIXI}	SCK2, SCK3 SIN2, SIN3		0	—	ns
SOT \rightarrow SCK \uparrow delay time	t_{SOVHI}	SCK2, SCK3 SOT2, SOT3		$3 t_{CP} - 70$	—	ns

Notes : • C_L is load capacity value of pins when testing.
 • t_{CP} is internal operating clock cycle time (machine clock) . Refer to "Clock Timing".

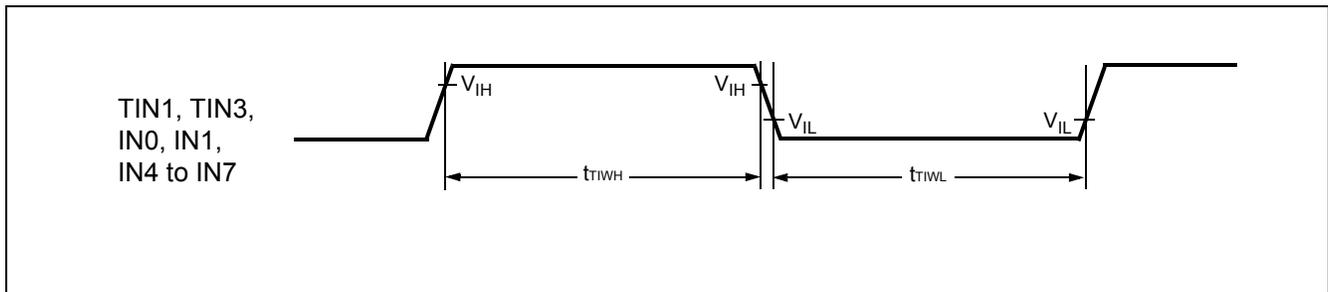


13.4.10 Trigger Input Timing
 $(T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, f_{CP} \leq 24\text{ MHz}, V_{SS} = AV_{SS} = 0\text{ V})$

Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Input pulse width	t_{TRGH} t_{TRGL}	INT8 to INT15, INT9R to INT11R, ADTG	—	$5 t_{CP}$	—	ns


13.4.11 Timer Related Resource Input Timing
 $(T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, f_{CP} \leq 24\text{ MHz}, V_{SS} = AV_{SS} = 0\text{ V})$

Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Input pulse width	t_{TIWH} t_{TIWL}	TIN1, TIN3, IN0, IN1, IN4 to IN7	—	$4 t_{CP}$	—	ns


13.4.12 Timer Related Resource Output Timing
 $(T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, f_{CP} \leq 24\text{ MHz}, V_{SS} = AV_{SS} = 0\text{ V})$

Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
CLK \uparrow \rightarrow T _{OUT} change time	t_{TO}	TOT1, TOT3, PPG4, PPG6, PPG8 to PPGF	—	30	—	ns

13.5 A/D Converter
 $(T_A = -40^\circ\text{C to } +125^\circ\text{C}, 3.0\text{ V} \leq \text{AVRH}, V_{CC} = \text{AV}_{CC} = 5.0\text{ V} \pm 10\%, f_{CP} \leq 24\text{ MHz}, V_{SS} = \text{AV}_{SS} = 0\text{ V})$

Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Resolution	—	—	—	—	10	bit	
Total error	—	—	—	—	± 3.0	LSB	
Nonlinearity error	—	—	—	—	± 2.5	LSB	
Differential nonlinearity error	—	—	—	—	± 1.9	LSB	
Zero reading voltage	V_{OT}	AN0 to AN14	$\text{AV}_{SS} - 1.5 \times \text{LSB}$	$\text{AV}_{SS} + 0.5 \times \text{LSB}$	$\text{AV}_{SS} + 2.5 \times \text{LSB}$	V	
Full scale reading voltage	V_{FST}	AN0 to AN14	$\text{AVRH} - 3.5 \times \text{LSB}$	$\text{AVRH} - 1.5 \times \text{LSB}$	$\text{AVRH} + 0.5 \times \text{LSB}$	V	
Compare time	—	—	1.0	—	16500	μs	$4.5\text{ V} \leq \text{AV}_{CC} \leq 5.5\text{ V}$
			2.0				$4.0\text{ V} \leq \text{AV}_{CC} < 4.5\text{ V}$
Sampling time	—	—	0.5	—	×	μs	$4.5\text{ V} \leq \text{AV}_{CC} \leq 5.5\text{ V}$
			1.2				$4.0\text{ V} \leq \text{AV}_{CC} < 4.5\text{ V}$
Analog port input current	I_{AIN}	AN0 to AN14	-0.3	—	+0.3	μA	
Analog input voltage range	V_{AIN}	AN0 to AN14	AV_{SS}	—	AVRH	V	
Reference voltage range	—	AVRH	$\text{AV}_{SS} + 2.7$	—	AV_{CC}	V	
Power supply current	I_A	AV_{CC}	—	3.5	7.5	mA	
	I_{AH}	AV_{CC}	—	—	5	μA	*
Reference voltage supply current	I_R	AVRH	—	600	900	μA	
	I_{RH}	AVRH	—	—	5	μA	*
Offset between channels	—	AN0 to AN14	—	—	4	LSB	

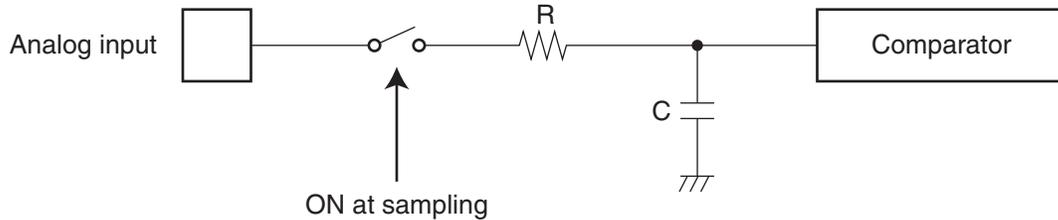
* : If A/D converter is not operating, a current when CPU is stopped is applicable ($V_{CC} = \text{AV}_{CC} = \text{AVRH} = 5.0\text{ V}$).

Notes on A/D Converter Section
■ About the external impedance of the analog input and its sampling time

A/D converter with sample and hold circuit. If the external impedance is too high to keep sufficient sampling time, the analog voltage charged to the internal sample and hold capacitor is insufficient, adversely affecting

A/D conversion precision. Therefore to satisfy the A/D conversion precision standard, consider the relationship between the external impedance and minimum sampling time and either adjust the register value and operating frequency or decrease the external impedance so that the sampling time is longer than the minimum value. Also if the sampling time cannot be sufficient, connect a capacitor of about 0.1 μF to the analog input pin.

· Analog input equivalence circuit



MB90F351E(S),MB90F351TE(S),MB90F352E(S),MB90F352TE(S),
MB90F356E(S),MB90F356TE(S),MB90F357E(S),MB90F357TE(S)

	R	C
$4.5\text{ V} \leq AV_{CC} \leq 5.5\text{ V}$	2.0 k Ω (Max)	16.0 pF (Max)
$4.0\text{ V} \leq AV_{CC} \leq 4.5\text{ V}$	8.2 k Ω (Max)	16.0 pF (Max)

MB90351E(S),MB90351TE(S),MB90352E(S),MB90352TE(S),
MB90356E(S),MB90356TE(S),MB90357E(S),MB90357TE(S),
MB90V340E-101/102/103/104

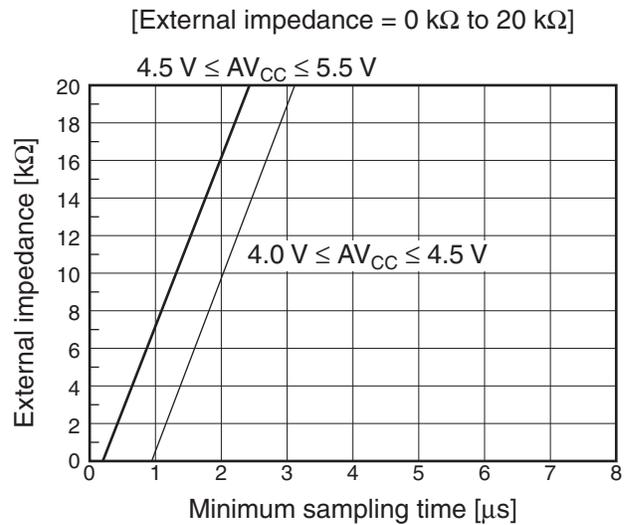
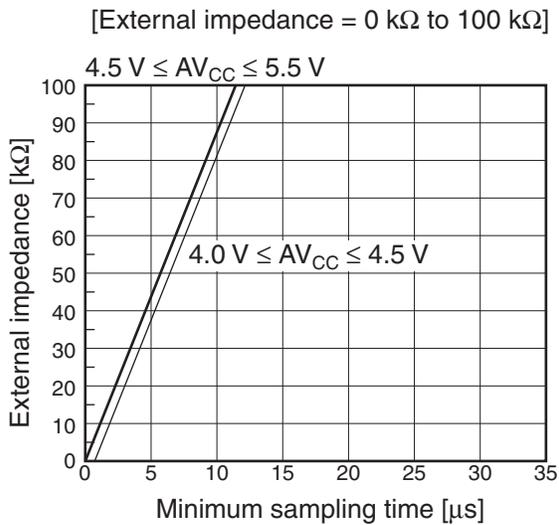
	R	C
$4.5\text{ V} \leq AV_{CC} \leq 5.5\text{ V}$	2.0 k Ω (Max)	14.4 pF (Max)
$4.0\text{ V} \leq AV_{CC} \leq 4.5\text{ V}$	8.2 k Ω (Max)	14.4 pF (Max)

Note : The value is reference value.

■ Flash memory device

· Relation between External impedance and minimum sampling time

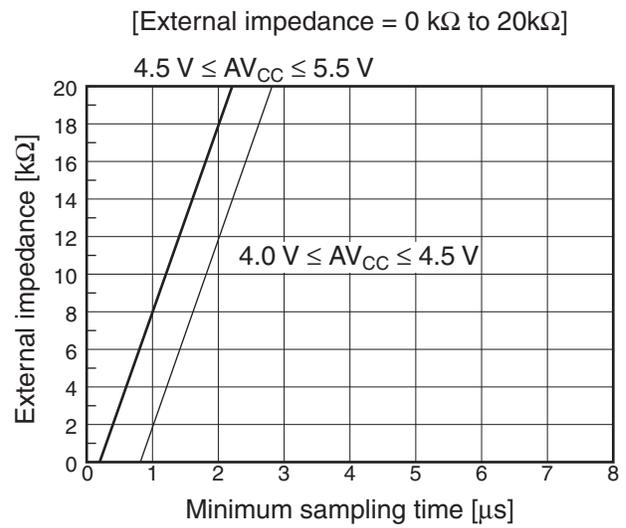
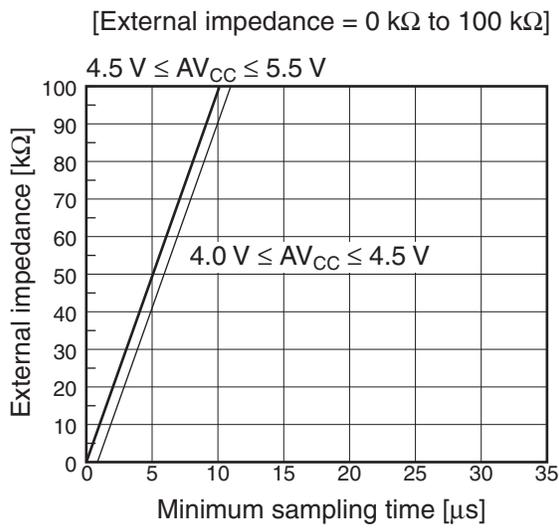
(MB90F351E(S),MB90F351TE(S),MB90F352E(S),MB90F352TE(S),
MB90F356E(S),MB90F356TE(S),MB90F357E(S),MB90F357TE(S))



■ MASK ROM device

· Relation between External impedance and minimum sampling time

(MB90351E(S),MB90351TE(S),MB90352E(S),MB90352TE(S),MB90356E(S),
MB90356TE(S),MB90357E(S),MB90357TE(S),MB90V340E-101/102/103/104)



■ About the error

Values of relative errors grow larger, as |AV_{RH} – AV_{SS}| becomes smaller.

Parameter	Conditions	Value			Unit	Remarks
		Min	Typ	Max		
Flash memory Data Retention Time	Average $T_A = +85^\circ\text{C}$	20	—	—	year	*

* : Corresponding value comes from the technology reliability evaluation result.

(Using Arrhenius equation to translate high temperature measurements test result into normalized value at +85°C)

14. Ordering Information

Part number	Package	Remarks
MB90F351EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	Flash memory products (64 Kbytes)
MB90F351ESPMC		
MB90F351TEPMC		
MB90F351TESPMC		
MB90F356EPMC		
MB90F356ESPMC		
MB90F356TEPMC		
MB90F356TESPMC		
MB90F352EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	Dual operation Flash memory products (128 Kbytes)
MB90F352ESPMC		
MB90F352TEPMC		
MB90F352TESPMC		
MB90F357EPMC		
MB90F357ESPMC		
MB90F357TEPMC		
MB90F357TESPMC		
MB90351EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	MASK ROM products (64 Kbytes)
MB90351ESPMC		
MB90351TEPMC		
MB90351TESPMC		
MB90356EPMC		
MB90356ESPMC		
MB90356TEPMC		
MB90356TESPMC		
MB90352EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	MASK ROM products (128 Kbytes)
MB90352ESPMC		
MB90352TEPMC		
MB90352TESPMC		
MB90357EPMC		
MB90357ESPMC		
MB90357TEPMC		
MB90357TESPMC		

(Continued)